MOSFETs Silicon P-Channel MOS (U-MOSVI)

TPCP8111

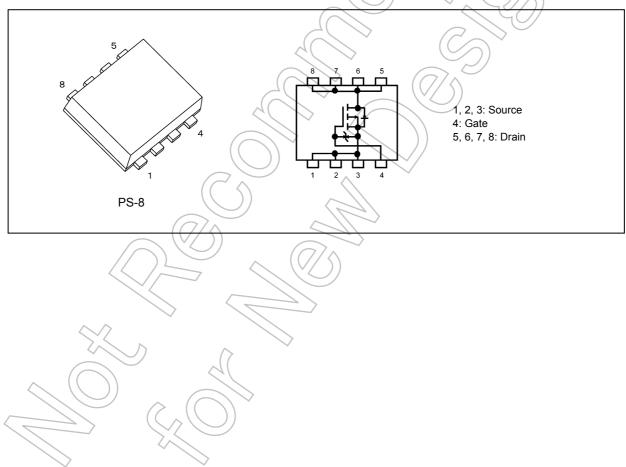
1. Applications

- Motor Drivers
- Mobile Equipment

2. Features

- (1) AEC-Q101 qualified
- (2) Small, thin package
- (3) Small gate charge: $Q_{SW} = 5.2 \text{ nC}$ (typ.)
- (4) Low drain-source on-resistance: $R_{DS(ON)} = 90 \text{ m}\Omega$ (typ.) ($V_{GS} = -10 \text{ V}$)
- (5) Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -60 \ V)$
- (6) Enhancement mode: $V_{th} = -2$ to $-3 V (V_{DS} = -10 V, I_D = -1 mA)$

3. Packaging and Internal Circuit



4. Absolute Maximum Ratings (Note) ($T_a = 25$ °C unless otherwise specified)

Characteristics			Symbol	Rating	Unit
Drain-source voltage			V _{DSS}	-60	V
Gate-source voltage			V _{GSS}	-20/+10	
Drain current (DC)		(Note 1)	ID C	-3	A
Drain current (pulsed)	·	(Note 1)	I _{DP}	-12	
Power dissipation	(t = 5 s)	(Note 2)	PD	1.96	W
Power dissipation	(t = 5 s)	(Note 3)	PD	0.94]
Single-pulse avalanche energy	·	(Note 4)	EAS	31.1	mJ
Avalanche current			IAR	-3	A
Channel temperature		(Note 5)	Tch	175	°C
Storage temperature		(Note 5)	(T _{stg})	-55 to 175]

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

5. Thermal Characteristics

Ch	aracteristics	(\bigcirc / \le)	Symbol	Max	Unit
Channel-to-ambient thermal resistance	(t = 5 s)	(Note 2)	R _{th(ch-a)}	76.5	°C/W
Channel-to-ambient thermal resistance	(t = 5 s)	(Note 3)	R _{th(ch-a)}	159.5	

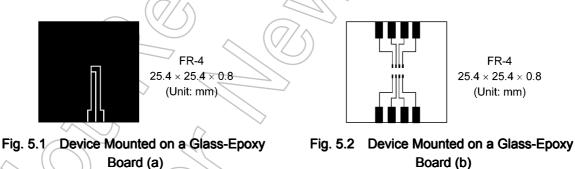
Note 1: Ensure that the channel temperature does not exceed 175 °C.

Note 2: Device mounted on a glass-epoxy board (a), Figure 5.1

Note 3: Device mounted on a glass-epoxy board (b), Figure 5.2

Note 4: V_{DD} = -25 V, T_{ch} = 25 °C (initial), L = 4.696 mH, R_G = 25 Ω , I_{AR} = -3 A

Note 5: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.



Note: This transistor is sensitive to electrostatic discharge and should be handled with care.

6. Electrical Characteristics

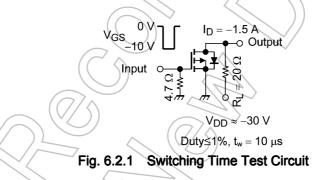
6.1. Static Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Gate leakage current	I _{GSS}	V _{GS} = -16/+10 V, V _{DS} = 0 V	_	_	±10	μA
Drain cut-off current	I _{DSS}	V _{DS} = -60 V, V _{GS} = 0 V	$\langle -$		-10	
Drain-source breakdown voltage	V _{(BR)DSS}	I _D = -10 mA, V _{GS} = 0 V	-60		—	V
Drain-source breakdown voltage (Note 6)	V _{(BR)DSX}	I _D = -10 mA, V _{GS} = 10 V	-50	$\left \right\rangle$	_	
Gate threshold voltage	V _{th}	V _{DS} = -10 V, I _D = -1 mA	-2	-2.5	-3	
Drain-source on-resistance	R _{DS(ON)}	V _{GS} = -6 V, I _D = -1.5 A	γ	99	158.4	mΩ
		V _{GS} = -10 V, I _D = -1.5 A	97	90	117	

Note 6: If a reverse bias is applied between gate and source, this device enters V_{(BR)DSX} mode. Note that the drainsource breakdown voltage is lowered in this mode.

6.2. Dynamic Characteristics ($T_a = 25$ °C unless otherwise specified)

Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Input capacitance	C _{iss}	V _{DS} = -10 V, V _{GS} = 0 V, f = 1 MHz	2<	760) —	pF
Reverse transfer capacitance	C _{rss}		\mathcal{A}	60		
Output capacitance	C _{oss}			90	_	
Switching time (rise time)	tr	See Figure 6.2.1.	29)	8	_	ns
Switching time (turn-on time)	t _{on}		\sim	25	_	
Switching time (fall time)	t _f))—	24	_	
Switching time (turn-off time)	t _{off}			126	_	



6.3. Gate Charge Characteristics ($T_a = 25$ °C unless otherwise specified)

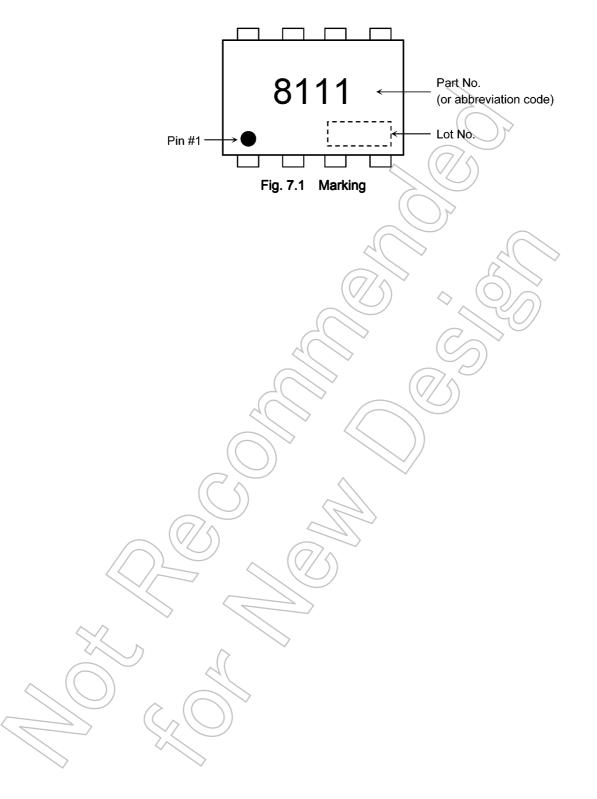
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Total gate charge (gate-source plus gate-drain)	Qg	$V_{DD}\approx -48~V,~V_{GS}$ = -10 V, I _D = -3 A	_	17.0	_	nC
Gate-source charge 1	Q _{gs1}			2.3	_	
Gate-drain charge	Q _{gd}		_	4.5	_	
Gate switch charge	Q _{SW}		—	5.2	_	

6.4. Source-Drain Characteristics (Ta = 25 °C unless otherwise specified)

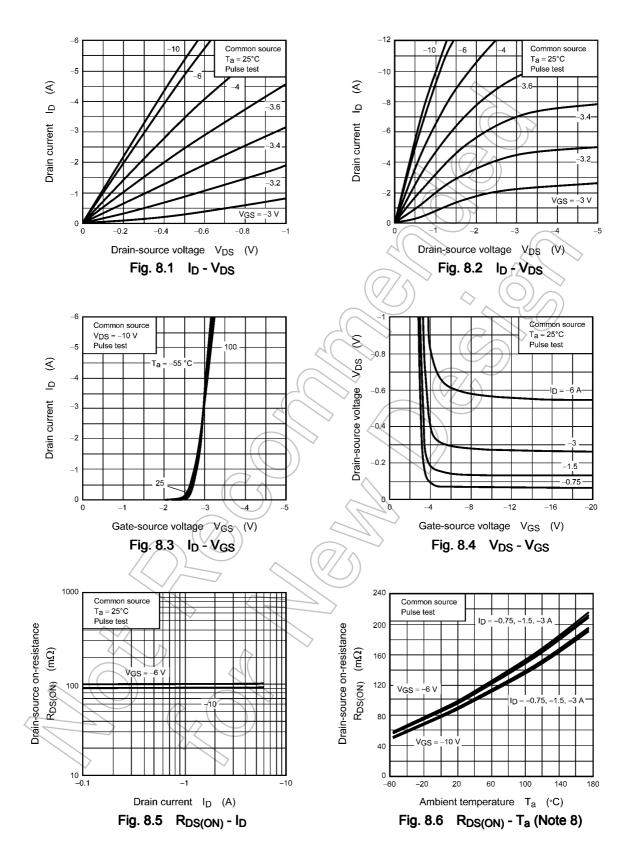
Characteristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Reverse drain current (pulsed) (Note	e 7) I _{DRP}	—	_	—	-12	А
Diode forward voltage	V _{DSF}	I _{DR} = -3 A, V _{GS} = 0 V			1.2	V

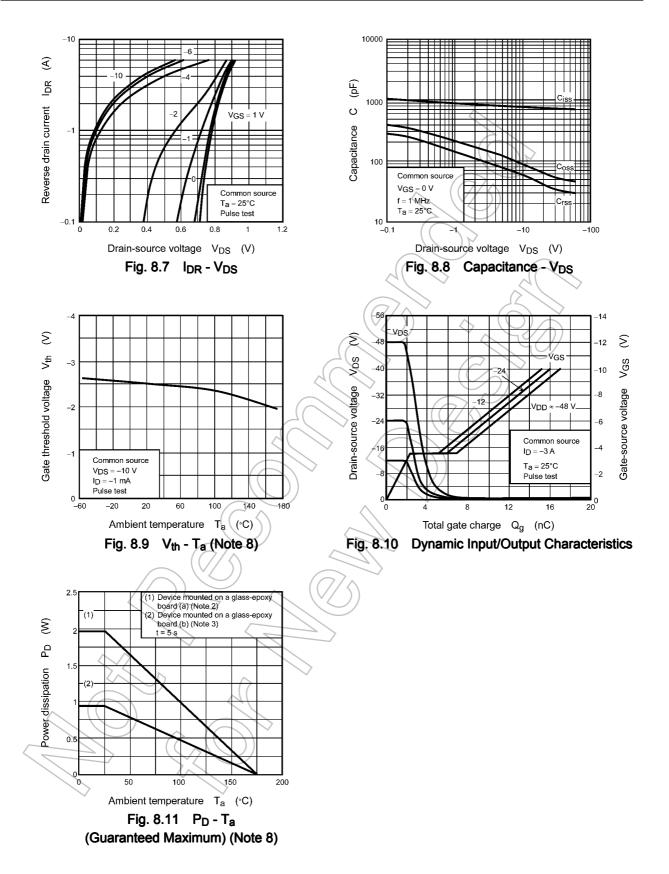
Note 7: Ensure that the channel temperature does not exceed 175 °C.

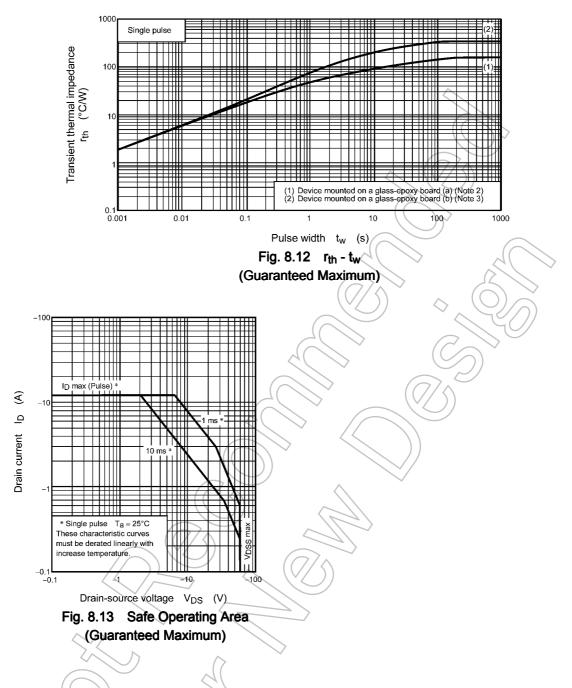
7. Marking



8. Characteristics Curves (Note)





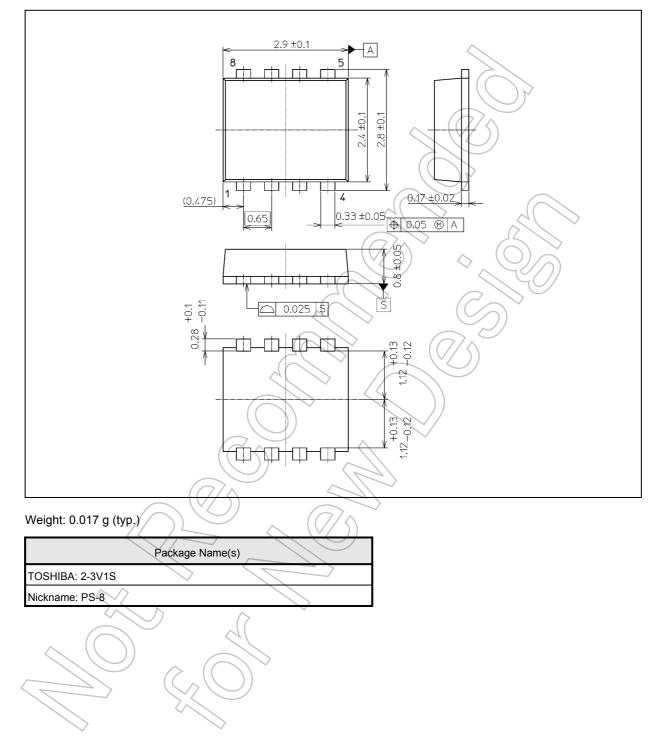


Note: The above characteristics curves are presented for reference only and not guaranteed by production test, unless otherwise noted.

Note 8: The definitions of the absolute maximum channel and storage temperatures are qualified per AEC-Q101.

Package Dimensions

Unit: mm



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